NSN 5961-00-038-6139

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-038-6139

Inclosure Material:

Metal

Overall Length:

Between 0.688 inches and 0.797 inches

Overall Diameter:

Between 0.885 inches and 0.915 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

Between 1.047 inches and 1.078 inches

Thread Size:

0.500 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 10.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

50.00 amperes source cutoff current

Power Rating Per Characteristic:

350.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius case

Special Features:

Junction pattern arrangement: npn

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Thread Series Designator:

Unf

Terminal Type And Quantity:

2 tab, solder lug and 1 wire hook

Specification Data:

81349-mil-s-19500/380 government specification

Shelf Life:

NI/o

NSN 5961-00-038-6139

Transistor - Page 2 of 2



ш	ın	10	<i>(</i>)+	Measure:	

--

Demilitarization:

No

Fiig:

A110a0